TOSHIBA Photocoupler PHOTORELAY

TLP3241

Measurement Instruments Logic IC Testers / Memory Testers Board Testers / Scanners

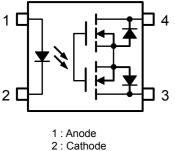
The TOSHIBA TLP3241 is a super small-outline photorelay, suitable for surface-mount assembly. The TLP3241 consists of a GaAlAs infrared-emitting diode optically coupled to a photo-MOS FET and housed in a 4-pin package.

Its characteristics also include low OFF-state current and low output pin capacitance, enabling it to be used in high-frequency measuring instruments.

Features

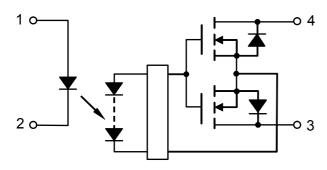
- 4 pin SSOP (SSOP4)
- : 1.8 mm high, 1.27 mm pitch
- 1-Form-A
- : 40 V (Min.)
- Peak off-state voltage : 3 mA (Max.) • Trigger LED current
 - : 140 mA (Max.)
- On-state current : 10 (Max.), 7 (Typ.) On-state resistance
- Output capacitance
- Isolation voltage
- : 1.3 pF (Max.), 0.7 pF (Typ.)
- : 1500 Vrms (Min.)

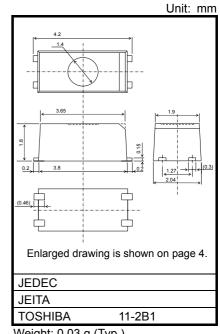
Pin configuration (top view)



- 3 : Drain
- 4 : Drain

Schematic





Weight: 0.03 g (Typ.)

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	I _F	30	mA
G	Forward current derating (Ta \ge 25°C)	∆l _F /°C	-0.3	mA/°C
Ц	Reverse voltage	VR	5	V
	Junction temperature	Tj	125	°C
	Off-State output terminal voltage	VOFF	40	V
Detector	On-State current	I _{ON}	140	mA
Dete	On-State current derating (Ta \ge 25°C)	∆l _{ON} /°C	-1.4	mA/°C
	Junction temperature	Tj	125	°C
Stora	Storage temperature range		-40~125	°C
Oper	Operating temperature range		-20~85	°C
Lead	Lead soldering temperature (10 s)		260	°C
Isola	tion voltage (AC, 1 min., R.H. \leq 60%) (Note 1)	BVS	1500	Vrms

(Note 1): Device considered a two-terminal device: Pins 1 and 2 shorted together, and pins 3 and 4 shorted together.

Caution

This device is sensitive to electrostatic discharge. When using this device, please ensure that all tools and equipment are earthed.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{DD}	_	_	32	V
Forward current	١ _F	_	_	20	mA
Operating temperature	T _{opr}	25		60	°C

Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	$I_F = 5 \text{ mA}$	1.15	1.30	1.45	V
LED	Reverse current	I _R	$V_R = 5 V$	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz		30		pF
Detector	Off-state current	IOFF	V _{OFF} = 35 V		10	200	pА
Dete	Capacitance	C _{OFF}	V = 0, f = 100 MHz, t<1s		0.7	1.3	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	I _{ON} = 100 mA	_	_	3	mA
Return LED current	I _{FC}	I _{OFF} = 1 μA	0.1	_	_	mA
On-state resistance	R _{ON}	I _{ON} = 140 mA, I _F = 5 mA, t < 1 s		7	10	Ω

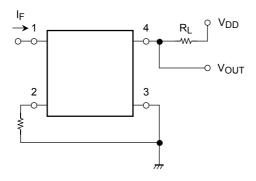
Isolation Characteristics (Ta = 25°C)

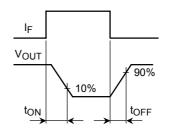
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	$V_S = 0 V$, f = 1 MHz	_	0.6	_	pF
Isolation resistance	R _S	$V_S = 500 \text{ V}, \text{ R.H.} \leq 60\%$	$5 imes 10^{10}$	10 ¹⁴	_	Ω
		AC, 1 minute	1500	_	_	Vrms
Isolation voltage	BVS	AC, 1 second (in oil)	_	3000	_	VIIIS
		DC, 1 minute (in oil)	—	3000		Vdc

Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t _{ON}	R _L = 200 Ω (Note 2)	_	26	200	
Turn-off time	tOFF	V _{DD} = 10 V, I _F = 5 mA		45	200	μS

(Note 2): switching time test circuit

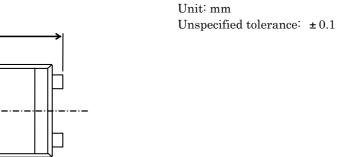


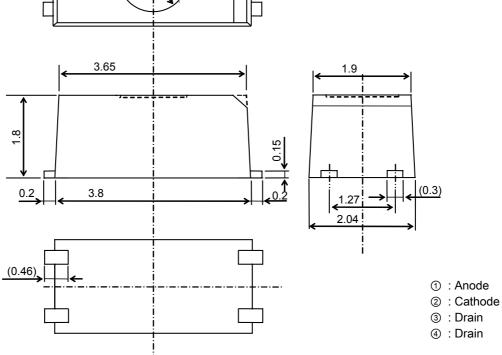


TOSHIBA

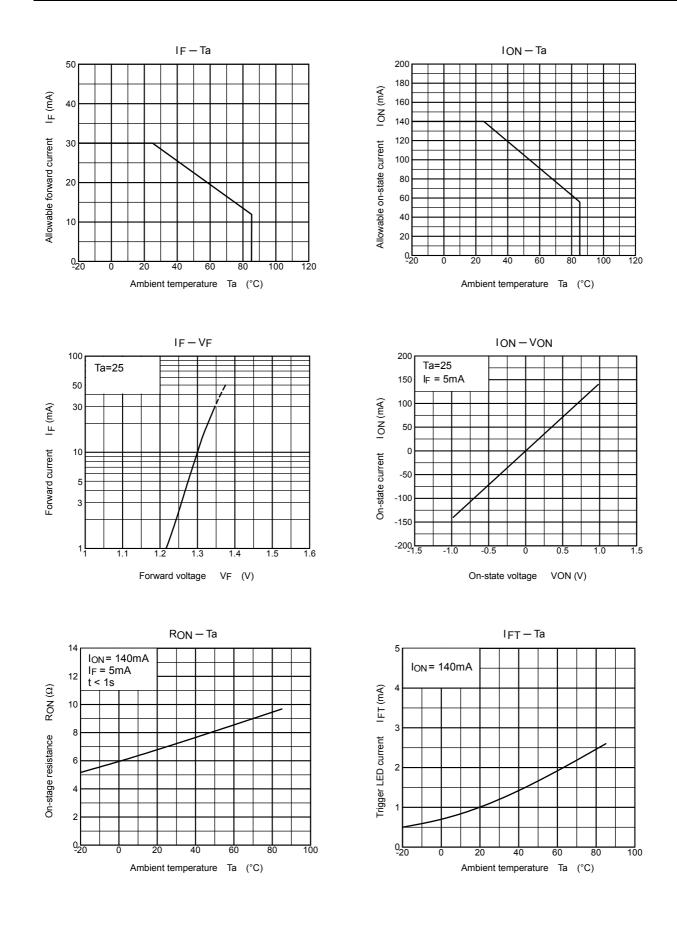
4.2 1.4

I

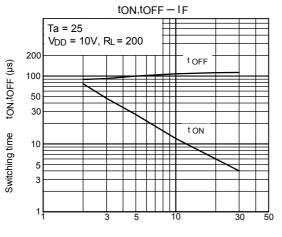




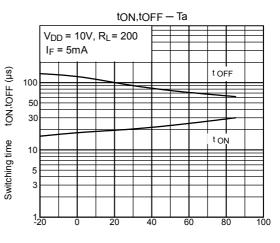
TOSHIBA



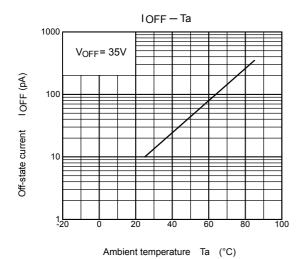
TOSHIBA







Ambient temperature Ta (°C)



RESTRICTIONS ON PRODUCT USE

030619EBC

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as

set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.
- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.